

Thick-Film Hybrid IC

2ch class-AB Audio Power IC 40W+40W

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Overview

The STK433-040N-E is a hybrid IC designed to be used in 40W × 2ch class AB audio power amplifiers.

Application

• Audio Power amplifiers

Features

- Pin-to-pin compatible outputs ranging from 40W to 150W.
- Output load impedance: $R_{L} = 6\Omega$ recommended.
- Allows the use of predesigned applications for standby and mute circuit.
- Miniature package.
- Allowable load shorted time: 0.3 second

Series model

	STK433-040N-E	STK433-060N-E	STK433-130N-E		
Output1 (10%/1kHz)	40W × 2ch	50W × 2ch	150W × 2ch		
Output2 (0.4%/20Hz to 20kHz)	25W × 2ch	35W × 2ch	100W × 2ch		
Max. rating V _{CC} (quiescent)	±38V	±46V	±71.5V		
Max. rating V _{CC} (6Ω)	±36V	±40V	±63V		
Recommended operating V_{CC} (6 Ω)	±24V	±27V	±44V		
Dimensions (excluding pin height)	47.0mm×25.	67.0mm×25.6mm×9.0mm			

	STK433-330N-E	STK433-840N-E	STK433-890N-E
Output1 (10%/1kHz)	150W × 3ch	40W × 4ch	80W × 4ch
Output2 (0.4%/20Hz to 20kHz)	100W × 3ch	25W × 4ch	50W × 4ch
Max. rating V _{CC} (quiescent)	±71.5V	±38V	±54V
Max. rating V_{CC} (6 Ω)	±63V	±36V	±47V
Recommended operating V_{CC} (6 Ω)	±44V	±25V	±34V
Dimensions (excluding pin height)	64.0mm×36.6mm×9.0mm	64.0mm×31.1mm×9.0mm	78.0mm×44.1mm×9.0mm

Specifications

Absolute Maximum Ratings at Ta = 25°C, Tc = 25°C unless otherwise specified

Parameter	Symbol	Conditions	Ratings	Unit
Maximum power supply voltage	V _{CC} max (0)	Non- signal	±38	V
	V _{CC} max (1)	Signal, $R_L \ge 6\Omega$	±36	V
	V _{CC} max (2)	Signal, $R_L \ge 4\Omega$	±30	V
Minimum operation supply voltage	V _{CC} min		±10	V
#13 Operating voltage *5	VST OFF max	#13 voltage	-0.3 to +5.5	V
Thermal resistance	θј-с	Per one power transistor	4.2	°C/W
Junction temperature	Tj max	Should satisfy Tj max and Tc max	150	°C
Operating substrate temperature	Tc max		125	°C
Storage temperature	Tstg		-30 to +125	°C
Allowable time for load short-circuit ts		V_{CC} = ±24V, R_L = 6 Ω , f = 50Hz P_O = 25W, 1ch drive	0.3	s

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

ORDERING INFORMATION

See detailed ordering and shipping information on page 11 of this data sheet.

Operating Characteristics at Tc = 25°C, $R_L = 6\Omega$ (Non-inductive Load), $Rg = 600\Omega$, VG = 30 dB

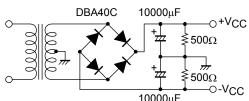
			C	onditions '	2			Ratings		
	Symbol	V _{CC} [V]	f [Hz]	P _O [W]	THD [%]		min	typ	max	Unit
*1	P _O 1	±24	20 to 20k		0.4		23	25		
	P _O 2	±24	1k		10			40		W
	P _O 3	±20	1k		1	R _L =4Ω		25		
*1	THD 1	±24	20 to 20k	- 0					0.4	0.4
	THD 2	±24	1k	5.0		VG=30dB		0.02		%
*1	f _L , f _H	±24		1.0		+0 -3dB		20 to 50k		Hz
	ri	±24	1k	1.0				55		kΩ
*3	V _{NO}	±29				Rg=2.2kΩ			1.0	mVrms
	lcco	±29				No load	15	30	70	mA
ру	ICST	±29							1.0	mA
	VN	±29					-70	0	+70	mV
*5	VST ON	±24				Stand-by		0	0.6	V
d *5	VST OFF	±24				Operation	2.5	3.0	5.5	V
	*1 *1 *3 by *5	*1 PO 1 PO 2 PO 3 *1 THD 1 THD 2 *1 fL, fH ri *3 VNO ICCO DY ICST VN *5 VST ON	*1 PO 1 ±24 PO 2 ±24 PO 3 ±20 *1 THD 1 ±24 THD 2 ±24 *1 f _L , f _H ±24 ri ±24 *3 VNO ±29 ICCO ±29 VN ±29 VN ±29 *5 VST ON ±24	Symbol V _{CC} f [V] [Hz] *1 P _O 1 ±24 20 to 20k P _O 2 ±24 1k P _O 3 ±20 1k *1 THD 1 ±24 20 to 20k THD 2 ±24 1k *1 f _L , f _H ±24 ri ±24 1k *3 V _{NO} ±29 I _{CCO} ±29 V _N ±29 *5 VST ON ±24	Symbol V _{CC} f P _O [W] *1	*1 PO 1 ±24 20 to 20k 0.4 PO 2 ±24 1k 10 PO 3 ±20 1k 1 *1 THD 1 ±24 20 to 20k THD 2 ±24 1k 5.0 *1 f _L , f _H ±24 1k 1.0 *3 VNO ±29 ICCO ±29 VN ±29 *5 VST ON ±24	$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	Symbol V _{CC} [V] f [Hz] P _O THD [%] min *1 P _O 1 ±24 20 to 20k 0.4 23 P _O 2 ±24 1k 10 10 P _O 3 ±20 1k 1 R _L =4Ω *1 THD 1 ±24 20 to 20k 5.0 VG=30dB THD 2 ±24 1k 1.0 +0 -3dB ri ±24 1k 1.0 +0 -3dB ri ±24 1k 1.0 Rg=2.2kΩ lCCO ±29 No load 15 OV ICST ±29 No load 15 *5 VST ON ±24 Stand-by Stand-by	Symbol V _{CC}	$\begin{array}{c ccccccccccccccccccccccccccccccccccc$

Note

- *1. 1channel operation.
- *2. All tests are measured using a constant-voltage supply unless otherwise specified
- *3. The output noise voltage is peak value of an average-reading meter with a rms value scale (VTVM). A regulated AC supply (50Hz) should be used to eliminate the effects of AC primary line flicker noise
- *4. Allowable time for load short-circuit and output noise voltage are measured using the specified transformer power supply.
- *5. Please connect PreVcc pin (#1 pin) with the stable minimum voltage. and connect so that current does not flow in by reverse bias.
- *6. In case of heat sink design, we request customer to design in the condition to have assumed market.
- * The case of this Hybrid-IC is using thermosetting silicon adhesive (TSE322SX).
- * Weight of HIC: (typ) 12.0g

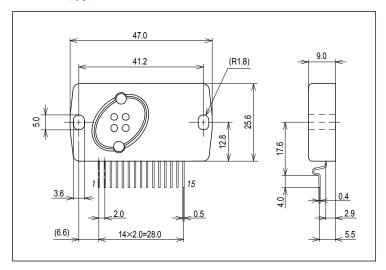
Outer carton dimensions (W×L×H): 452mm×325mm×192mm

Specified transformer power supply (Equivalent to MG-200)



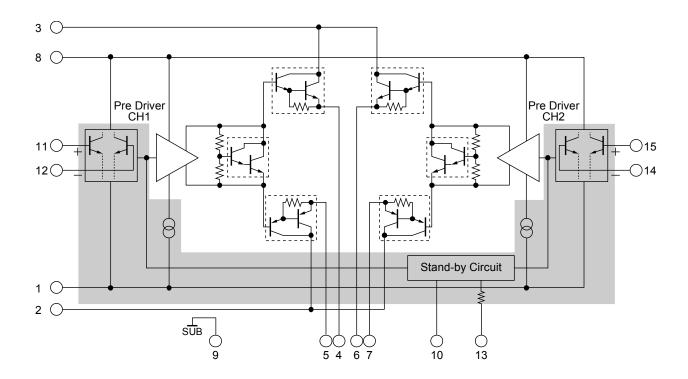
Package Dimensions

unit: mm (typ)

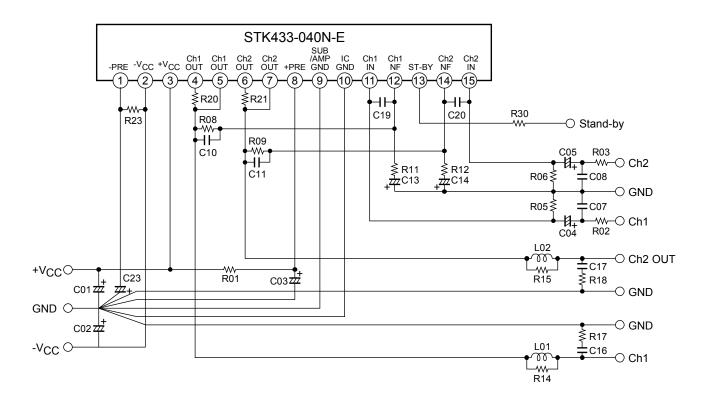


RoHS directive pass

Equivalent Circuit

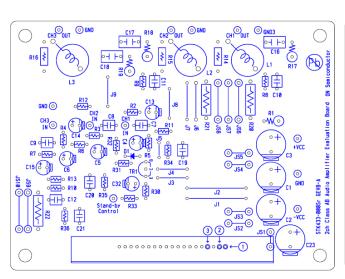


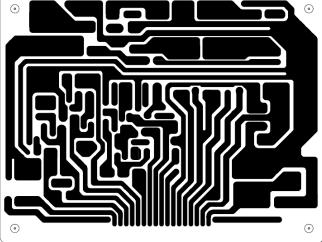
Application Circuit



PCB Layout Example

Top view





STK433-040N-E/060N-E/130N-E/330N-E PCB PARTS LIST

PCB Name: STK433 - 000Sr GEVB - A

Location No).									
(*2) 2ch Amp doesi parts of (RATING	TING Component							
				STK433-						
Hybrid IC#1 Pin Position		-	040N-E	060N-E	130N-E/ 330N-E					
R01		100Ω, 1W		0						
R02, R03, (R04)		1kΩ, 1/6W		0						
R05, R06, (R07), R08, R09	, (R10)	56KΩ, 1/6W		0						
R11, R12, (R13)		1.8KΩ, 1/6W		0						
R14, R15, (R16)		4.7Ω, 1/4W		0						
R17, R18, (R19)		4.7Ω, 1W		0						
R20, R21, (R22)		0.22Ω, 2W	0	0	-					
		0.22Ω, 5W	-	-	0					
C01, C02, C03, C23		100μF, 100V	0							
C04, C05, (C06)		2.2μF, 50V		0						
C07, C08, (C09)		470pF, 50V		0						
C10, C11, (C12)		3pF, 50V		0						
C13, C14, (C15)		10μF, 16V	0							
C16, C17, (C18)		0.1μF, 50V	0							
C19, C20, (C21)		***pF, 50V	100pF	56pF	N.C.					
R34, R35, (R36)		Jumper		Short						
L01, L02, (L03)		3μΗ		0						
	Tr1	VCE ≥ 75V, IC ≥ 1mA		0						
	D1	Di		0						
Stand-By	R30 (*2)	2.7kΩ, 1/6W		∘ (*2)						
Control	R31	33kΩ, 1/6W		0						
Circuit	R32	1kΩ, 1/6W		0						
	R33	2kΩ, 1/6W		0						
	C32	33μF, 10V	0							
J1, J2, J3, J4, J5, J6, J8, J9)	Jumper	0							
J7, JS2, JS3, JS4, JS5, JS JS8, JS9	7	-	-							
JS6, JS10		Jumper	0							
JS1 (R23)		100Ω, 1W		0						

^(*1) STK433-040N-E/060N-E/130N-E (2ch Amp) doesn't mount parts of (

^(*2) Recommended standby circuit is used.

Recommended external components

STK433-040N-E/060N-E/130N-E/330N-E

3111733-070	IN-L/OUDIN-L/	15014-1/55014-1	T							
Parts	Recommended	Circuit purpose	Above	Below						
Location	value	Official purpose	Recommended value	Recommended value						
R01, R23	100Ω/1W	Resistance for Ripple filter. (Fuse resistance is recommended.	Short-through current	Short-through current						
		Ripple filter is constituted with C03, C23.)	may decrease at	may increase at high						
			high frequency.	frequency.						
R02, R03, R04	1kΩ	Resistance for input filters.	-	-						
R05, R06, R07	56kΩ	Input impedance is determined.	Output neutral voltage(VN) shift.							
			(It is referred that R05=	R08, R06=R09)						
R08, R09, R10	56kΩ	Voltage Gain (VG) is determined with R11, R12, R13	-	-						
R11, R12, R13	1.8kΩ	Voltage Gain (VG) is determined with R8, R9, R10	It may oscillate.	With especially no						
		(As for VG, it is desirable to set up by R11, R12, R13)	(Vg < 30dB)	problem						
R14, R15, R16	4.7Ω	Resistance for oscillation prevention.	-	-						
R17, R18, R19	4.7Ω/1W	Resistance for oscillation prevention.	-	-						
R20, R21, R22	0.22Ω/2W	This resistance is used as detection resistance of the protection								
	(040N-E,060N-E)	circuit application.	Decrease of	It may cause thermal						
	0.22Ω/5W		Maximum output	runaway						
	(130N-E,330N-E)		Power	,						
R30	Note *5	Select Restriction resistance, for the impression voltage of #17	(Stand-By) pin' must no	t exceed the maximun						
		rating.								
C01, C02	100μF/50V	Capacitor for oscillation prevention.								
		Locate near the HIC as much as possible.								
		Power supply impedance is lowered and stable operation of	-	-						
		the IC is carried out. (Electrolytic capacitor is recommended.)								
C03, C23	100μF/50V	Decoupling capacitor	The change in the Ripp	le ingredient mixed in						
		The Ripple ingredient mixed in an input side Is removed from a	an input side from a por	wer supply line						
		power supply line. (Ripple filter is constituted with R01, R23.)								
C04, C05, C06	2.2μF/50V	Input coupling capacitor.(for DC current prevention.)		-						
C07, C08, C09	470pF	Input filter capacitor								
		A high frequency noise is reduced with the filter constituted by		-						
		R02, R03, R04								
C10, C11, C12	3pF	Capacitor for oscillation prevention.	It may oscillate.							
C13, C14, C15	10μF/10V	Negative feedback capacitor.	The voltage gain (VG)	The voltage gain (VG						
		The cutoff frequency of a low cycle changes.	of low frequency is	of low frequency						
		$(fL = 1/(2\pi \cdot C13 \cdot R11))$	extended. However,	decreases.						
			the pop noise at the							
			time of a power							
			supply injection also							
			becomes large.							
C16, C17, C18	0.1μF	Capacitor for oscillation prevention.	It may oscillate.							
C19, C20, C21	100pF (040N-E)	Capacitor for oscillation prevention.	It may oscillate.							
	56pF (060N-E)									
	N.C. (130N-E,									
	330N-E)									
L01, L02, L03	3μΗ	Coil for oscillation prevention.	With especially	It may oscillate.						
			no problem							

Pin Layout

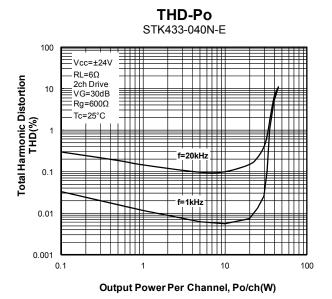
15 FK433-000N/-100N/-300NSFPIN Lavo	N/-100N/-300Nsr Pin Layout	STK433-000N/
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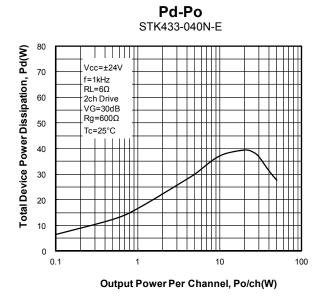
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	1	2	3	4	5	6	7	8	9	10	11	12	13	14	15				
(Size) 47.0mm×25.6mm×9.0mm						2cl	h clas	sAB/	2.00r	nm									
STK433-040N 40W/JEITA	-	-	+	0	0	0	0	+			Ι	N	S	N	Ι				
STK433-060N 50W/JEITA	Р	٧	٧	U	U	U	U	Р	S	G	N	F	Т	F	N				
	R	С	С	Т	Т	Т	Т	R	U	N	1	1	Α	1	1				
	E	С	С	/	/	/	/	Е	В	D	С	С	N	С	С				
(Size) 67.0mm×25.6mm×9.0mm				C H	С	C H	C H				H 1	H 1	D I	H 2	H 2				
STK433-130N 150W/JEITA				1	1	2	2				'	ļ '	В	_	_				
				+	-	+	-						Υ						
	1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16	17	18	19
(Size) 64.0mm×36.6mm×9.0mm			I					3c	h clas	sAB/	2.00r	nm	l	l		l	l	l	
STK433-330N 150W/JEITA	-	-	+	0	0	0	0	+			1	N	S	N	ı	ı	N	0	0
	Р	٧	٧	U	U	U	U	Р	s	G	N	F	Т	F	N	N	F	U	U
	R	С	С	Т	Т	Т	Т	R	U	Ν	1	1	Α	1	1	1	1	Т	Т
	E	С	С	1	1	1	1	Е	В	D	С	С	N	С	С	С	С	1	/
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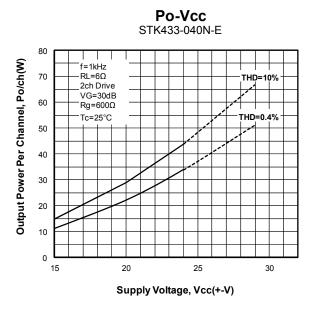
[STK433-000N/-100N/-800Nsr Pin Layout]

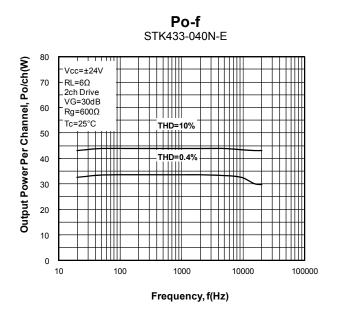
[31K433-000N/-100N/-60	UINS	<u>ы г</u>	111 L	ayu	սւյ																		
	1	2	3	4	5	6	7	8	9	10	11	12	13	14	15								
(Size) 47.0mm×25.6mm×9.0mm						2c	h clas	sAB/	2.00r	nm													
STK433-040N 40W/JEITA	-	-	+	0	0	0	0	+			I	Ν	S	N	I								
STK433-060N 50W/JEITA	Р	٧	٧	U	U	U	U	Р	S	G	N	F	Т	F	N								
	R	С	С	T	T	T	T	R	U	N	1	/	Α	1	1								
	E	С	С	C	C	/ C	C /	Е	В	D	C H	C H	N D	С	C H								
(Size) 67.0mm×25.6mm×9.0mm				Н	Н	Н	Н				1	п 1		2	2								
STK433-130N 150W/JEITA				1	1	2	2					·	В	_	_								
				+	-	+	-						Υ										
	1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16	17	18	19	20	21	22	23
(Size) 64.0mm×31.1mm×9.0mm										4c	h clas	sAB/	2.00r	nm									
STK433-840N 40W/JEITA	-	-	+	0	0	0	0	+			Ι	N	S	N	1	N	Ι	Ι	N	0	0	0	0
	Р	٧	٧	U	U	U	U	Р	S	G	N	F	Т	F	N	F	N	N	F	U	U	U	U
	R	С	С	Т	Т	Т	T	R	U	Ν	1	1	Α	1	1	1	1	1	1	Т	Т	Т	Т
	Е	С	С	/	/	/	/	Е	В	D	С	С	N	С	С	С	С	С	С	1	1	/	/
(Size) 78.0mm×44.1mm×9.0mm				С	С	С	С				Н	H	D	Н	Н	Н	Н	Н	Н	C	C	С	C
STK433-890N 80W/JEITA	1			H 1	H	H 2	H 2				1	1	В	2	2	3	3	4	4	H 3	H 3	H 4	H 4
STR433-890N 80W/JEITA	-			+	<u>'</u>	+	_						Y							-	+	-	+
	-												'										
<u> </u>	-																						
																							1

Characteristic of Evaluation Board









A Thermal Design Tip For STK433-040N-E Amplifier

[Thermal Design Conditions]

The thermal resistance (θ c-a) of the heat-sink which manages the heat dissipation inside the Hybrid IC will be determined as follow:

(Condition 1) The case temperature (Tc) of the Hybrid IC should not exceed 125°C

$$Pd \times \theta c-a + Ta < 125^{\circ}C \qquad (1)$$

Where Ta: the ambient temperature for the system

(Condition 2) The junction temperature of each power transistor should not exceed 150°C

$$Pd \times \theta c-a + Pd/N \times \theta j-c + Ta < 150^{\circ}C$$
 (2)

Where N: the number of transistors (two for 1 channel, ten for channel)

 θ_{j-c} : the thermal resistance of each transistor (see specification)

Note that the power consumption of each power transistor is assumed to be equal to the total power dissipation (Pd) divided by the number of transistors (N).

From the formula (1) and (2), we will obtain:

The value which satisfies above formula (1)' and (2)' will be the thermal resistance for a desired heat-sink. Note that all of the component except power transistors employed in the Hybrid IC comply with above conditions.

[Example of Thermal Design]

Generally, the power consumption of actual music signals are being estimated by the continuous signal of $1/8 P_O$ max. (Note that the value of $1/8 P_O$ max may be varied from the country to country.) (Sample of STK433-040N-E; $25W\times2ch$)

If V_{CC} is $\pm 24V$, and R_L is 6Ω , then the total power dissipation (Pd) of inside Hybrid IC is as follow;

Pd = 26W (at 3.13W output power, 1/8 of P_O max)

There are four (4) transistors in Audio Section of this Hybrid IC, and thermal resistance (θ j-c) of each transistor is 4.2°C/W. If the ambient temperature (Ta) is guaranteed for 50°C, then the thermal resistance (θ c-a) of a desired heat-sink should be;

From (1)'
$$\theta c-a < (125 - 50)/26$$

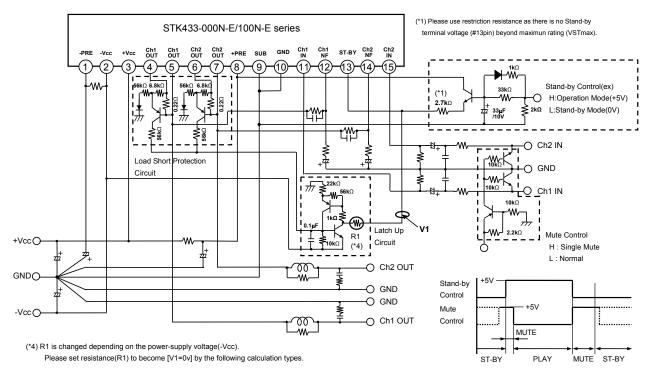
 < 2.88
From (2)' $\theta c-a < (150 - 50)/26 - 4.2/4$
 < 2.79

Therefore, in order to satisfy both (1)' and (2)', the thermal resistance of a desired Heat-sink will be 2.79°C/W.

[Note]

Above are reference only. The samples are operated with a constant power supply. Please verify the conditions when your system is actually implemented.

STK433-000N-E/100N-E series Stand-by Control & Mute Control & Load-Short Protection Application

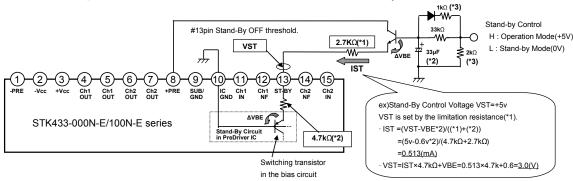


[STK433-000N-E/100N-E series Stand-By Control Example]

[Feature]

- The pop noise which occurs to the time of power supply on/off can be improved substantially by recommendation Stand-By Control Application.
- Stand-By Control can be done by additionally adjusting the limitation resistance to the voltage such as micom, the set design is easy.

(Reference circuit) STK433-000N-E/100N-E series test circuit To Stand-By Control added +5V.



[Operation explanation] #13pin Stand-By Control Voltage VST

(1) Operation Mode

The switching transistor in the bias circuit turns on and places the amplifier into the operating mode, when 13pin (VST) voltage added above 2.5V (typ 3.0V).

(2) Stand-By Mode

When 13pin (VST) voltage is stopped (= 0V), the switching transistor in the bias circuit turn off, placing the amplifier into the standby mode.

- (*1) The current limiting resistor must be used to ensure that stand-by pin (13pin) voltage does not exceed its maximum rated value VST max.
- (*2) The pop noise level when the power is turned on can be reduced by setting the time constant with a capacitor in operating mode.
- (*3) Determines the time constant at which the capacitor (*2) is discharged in stand-by mode.

ORDERING INFORMATION

Device	Package	Shipping (Qty / Packing)
STK433-040N-E	SIP15 (Pb-Free)	25 / Bulk Box

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